



Giornate Nazionali EIC_NET

Corigliano-Rossano, June 22-23 2023

ePIC Silicon Vertex Tracker and INFN R&D

- ePIC SVT layout and concept
- from EIC Silicon Consortium to ePIC SVT DSC
- activity and plans in the INFN groups

D. Colella and D. Elia (Bari)

ePIC SVT layout and concept

Current ePIC SVT layout:

- 3 **Inner Barrel (IB)** layers (curved silicon layers, **L0-L2**)
- 2 **Outer Barrel (OB)** layers (stave-based layers, **L3-L4**)
- 5 **Disks** on each side of the IP (**E(H)D0-E(H)D4**)

October 2022 geometry

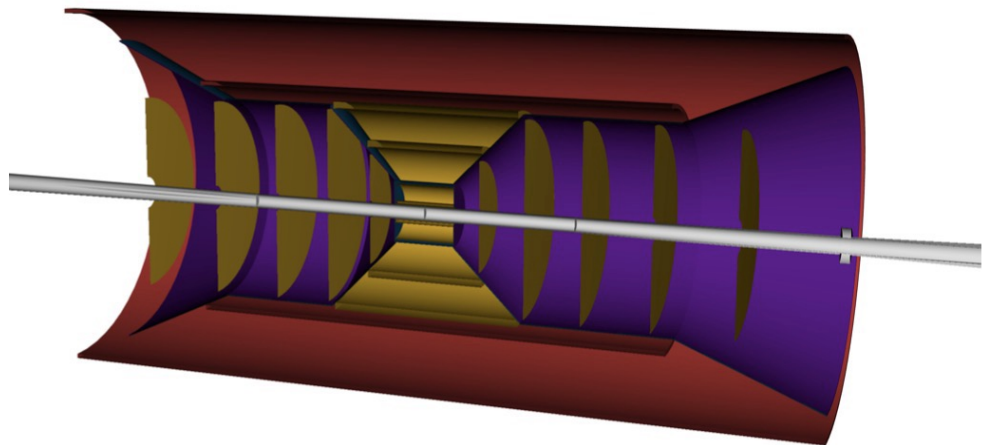
Total (active) area: $\sim 8.5 \text{ m}^2$

Updated barrel reference geometry:

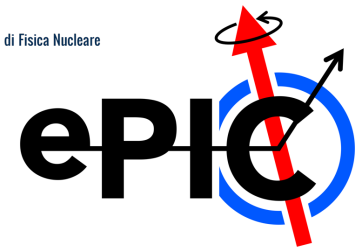
- 2 curved silicon vertex layers, $r = 36, 48 \text{ mm}$, $l = 270 \text{ mm}$
- 1 curved silicon dual purpose layer $r = 120 \text{ mm}$, $l = 270 \text{ mm}$
- 1 stave-based sagitta layer $r = 270 \text{ mm}$, $l = 540 \text{ mm}$
- 1 stave-based outer layer $r = 420 \text{ mm}$, $l = 840 \text{ mm}$

Updated disk reference geometry:

- 5 disks on either side of the nominal IP
 - $z = -250, -450, -650, -900, -1150 \text{ mm}$
 - $z = 250, 450, 700, 1000, 1350 \text{ mm}$
- inner radii $\geq 36 \text{ mm}$, outer radii $\leq 430 \text{ mm}$



ePIC SVT layout and concept



ePIC SVT concept in a nutshell:

- **ITS3-like IB layers:**
 - ✓ Use the ITS3 wafer-scale sensor
 - ✓ Adapt ITS3 detector concept to the (larger) EIC radii
 - *Mechanics, services and cooling of ePIC SVT inner barrel layers need specific development*
- **OB layers and Disks:**
 - ✓ EIC Large Area Sensor (LAS), i.e. ITS3 sensor size optimised for high yield, low cost, large area coverage
 - ✓ Conventional design of carbon fibre support structures (i.e. staves, disks), with integrated cooling and electrical interfaces

See also **ePIC SVT Wiki pages**: <https://wiki.bnl.gov/EPIC/index.php?title=SiConsortium>

ePIC SVT layout and concept

ePIC SVT Inner Barrel (IB) layers

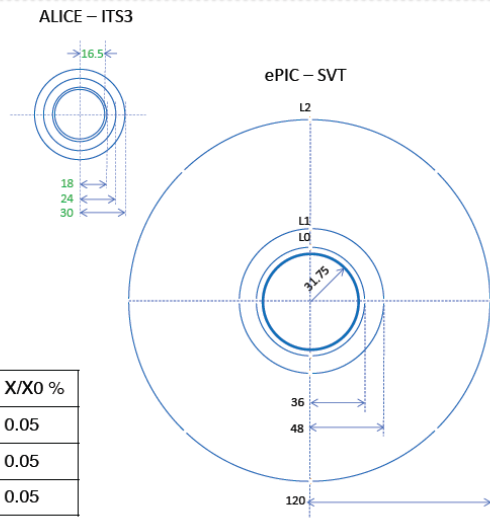
- Re-use ITS3 wafer-scale sensor

- L0: 3x12 RSU + endcaps
- L1: 4x12 RSU + endcaps
- L2: 5x12 RSU + endcaps

- Number of sensors per layer

- L0: 4
- L1: 4
- L2: 8

| ePIC SVT IB | r [mm] | l [mm] | X/X0 % |
|-------------|--------|--------|--------|
| L0 | 36 | 270 | 0.05 |
| L1 | 48 | 270 | 0.05 |
| L2 | 120 | 270 | 0.05 |



Laura Gonella | ePIC SVT kickoff meeting | 9 June 2023

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ePIC SVT Outer Barrel (OB) layers and disks

- EIC-LAS sensor = 1 segment with N RSU + endcaps.

- N to be defined based on yield and cost, acceptance and coverage, manufacturing constrains.

- Possibly add some changes in the endcaps.

- e.g. if needed for powering and data transmission.

| ePIC SVT OB | r [mm] | l [mm] | X/X0 % |
|-------------|--------|--------|--------|
| L3 | 270 | 540 | 0.25 |
| L4 | 420 | 840 | 0.55 |

Disks nomenclature:
ED0 - ED4 in electron going direction (-z)
HD0 - HD4 in proton going direction (+z)

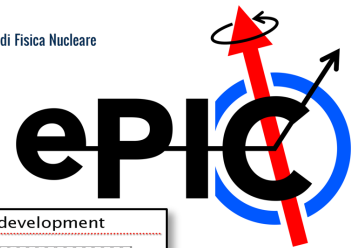
Disk inner opening:
beam pipe radius + clearance for beam pipe bake out (5 mm);
offset wrt disk center where beam pipe fans out

| ePIC SVT Disks | +z [mm] | -z [mm] | r_out [mm] | X/X0 % |
|----------------|---------|---------|------------|--------|
| Disk 0 | 250 | -250 | 240 | 0.24 |
| Disk 1 | 450 | -450 | 420 | 0.24 |
| Disk 2 | 700 | -650 | 420 | 0.24 |
| Disk 3 | 1000 | -900 | 420 | 0.24 |
| Disk 4 | 1350 | -1150 | 420 | 0.24 |

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ePIC SVT layout and concept



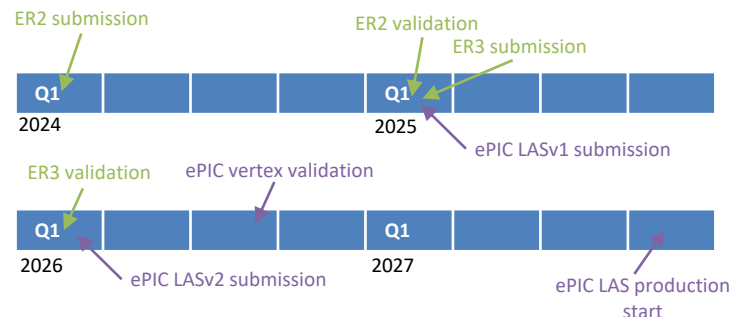
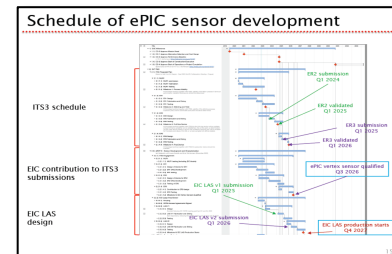
ePIC SVT relevant timeline:

- **R&D phase ongoing:**

- ✓ EIC vertex sensor qualification expected in September 2026, concurrent with ALICE-ITS3
- ✓ EIC Large Area Sensor production start (not before) ~February 2027

- **Construction phase will (mostly) follow R&D:**

- ✓ CD-3 (Approve Start of Construction/Execution) currently anticipated for Spring 2025
- ✓ SVT construction estimated ~3-4 years in a technically driven schedule



EIC Silicon Consortium

Past and ongoing activities:

- coordinating effort towards the EIC silicon tracker:
 - ✓ supporting the ePIC Tracking WG and R&D activities on the silicon detectors
 - ✓ moving to the **ePIC Si-Vertex Tracker DSC**, open to additional groups and institutions
- weekly Coordination meetings, on Monday @12pm EDT:
 - ✓ indico: <https://indico.bnl.gov/category/387/>
 - ✓ promoting activity progress and coordinating institutional relationship
 - ✓ people: N. Apadula (LBL), **G. Contin** (INFN Trieste), G. Deptuch (BNL), L. Greiner (LBL), **D. Elia** (INFN Bari), L. Gonella (Birmingham), P. Jones (Birmingham), I. Sedgwick (RAL), E. Sichtermann (LBL)
- bimonthly General meetings, on Tuesday @12pm EDT:
 - ✓ indico: <https://indico.bnl.gov/category/386/>, mailing list: eic-rd-silicon-l@lists.bnl.gov
 - ✓ SC activity progress reports (eRD104, eRD111 and eRD113 projects, in rotation)
 - ✓ now becoming **“ePIC SVT DSC meetings”** (change in the mailing list will happen soon)

Based on discussions in the EIC SC on ~Jan/Feb:

- SVT DSC coming together “*to develop, construct and operate a well-integrated, large-acceptance, low-mass, high resolution tracking and vertexing solution for ePIC based on Monolithic Active Pixel Sensors (MAPS) in 65 nm technology*”
- by consensus of the initial membership, Laura (*technical coordinator*) and Ernst (*DSC leader*) will serve in the startup phase
- imperative to advance earlier initial discussions in the EIC SC on:
 - ✓ who will participate (R&D phase, and during construction)?
 - ✓ who will do what?
 - ✓ what resources are available to / within the SVT-DSC?
 - ✓ what is not covered or missing?

ePIC SVT DSC

ePIC SVT DSC kickoff meeting:

- June 9: <https://indico.bnl.gov/event/19823/>
- main goals:
 - ✓ agreed-on work packages
 - ✓ how the work will be shared during the remainder of the R&D phase and during construction
 - ✓ create common understanding of the current SVT baseline to facilitate efficient collaboration

10:25 → 12:45 Interests and planned contributions to the ePIC SVT

10:25 UK groups

Speaker: Georg Viehhauser (Oxford U.)

UK SVT kick-off.pdf UK SVT kick-off.pptx

10:50 Korean groups (TBC)

Speaker: Youngil Kwon (Yonsei Univ.)

11:00 Czech Republic groups

Speaker: Lukas Tomasek

TOMASEK_ePIC-SV...

11:15 Oak Ridge National Laboratory

Speakers: Joachim Schambach (Oak Ridge National Laboratory), Kenneth Read (Oak Ridge National Laboratory)

EIC SVT-ORNL.pdf

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20230609_SVTKick...

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ePIC-SVT-DSC-0623...

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BNL_ePIC_SVT_060...

12:20 Los Alamos National Laboratory

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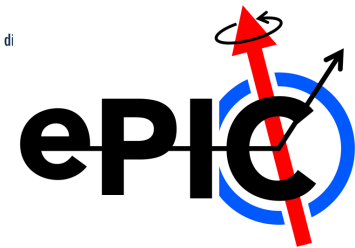
LANL_EIC_SVT_pro...

12:30 Lawrence Berkeley National Laboratory

Speaker: Ernst Sichtermann (Lawrence Berkeley National Laboratory)

ePIC-SVT - Berkeley...

ePIC SVT DSC



WP1 Sensor development

Design
•Contribution to ITS3 ER2 and ER3
•EIC LAS v1, v2, production
Characterisation
•Lab, test beam, irradiations

(Most closely related to eRD113 project R&D)

WP2 Mechanics and cooling

•Mechanics of bent vertex layers
•Air cooling for vertex layers
•Support structure for sagitta layers and disks
•Cooling for sagitta layers and disks

(eRD111 project R&D)

WP3 Sensors electrical interfaces

•FPC from sensors to end of layers/disks
•Wire bonding (sensor to FPC)
•Connection to services (FPC to services)

(Aspects within eRD111 project R&D scope)

WP4 Readout and powering

•Power regulator; SP architecture (data transmission, current source, grounding)
•On-/off-sensor data handling, full chain until FELIX

(eRD104 project R&D)

WP5 Integration

•Overall mechanical support and integration
•Detector cabling (i.e. cables and routing)
•Power supplies and cooling plant
•Close collaboration with project engineers

(Aspects within eRD111 project R&D scope)

WP6 Simulations

•Link to tracking working group
•(Detailed) SVT detector description

WP7 Interlocks, slow control, run control, monitoring

To be activated later on

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- INFN contribution [here](#):
 - ✓ planned contributions: next slide
 - ✓ ongoing R&D activities: following slides

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ePIC-SVT - Berkeley...

Planned contributions to the ePIC SVT

- Funding and labor force
 - ✓ Project not officially funded yet, ~1M\$ in-kind contribution to SVT is foreseen for construction phase
 - ✓ Scientific staff ramping up to 3-5 FTE during R&D phase + technical personnel. Expected to grow for construction, to be defined
- R&D for vertex layers
 - ✓ **Bending and interconnections** based on bending/interconnection/prototyping activities for ITS3
 - ✓ General contribution on **sensor test and characterization** (also connected to the eRD111 targets for this year)
 - ✓ Contribution to **FPC development and testing**
 - ➔ overall effort **to be better defined** based on effective dedicated labor force growing in the groups
- Construction of vertex layers
 - ✓ Possible **in-kind** contribution to **silicon production runs, thinning and dicing**
 - ✓ Considering specific construction items compatible with ongoing R&D and available labor force, for example:
 - ✓ On-wafer large-area **sensor probe testing**
 - ✓ **FPC** production and integration
 - ✓ Participation in **chip bending and layer integration**
 - **To be decided** based on the other groups' interests and the available resources

ePIC SVT DSC



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June 9th 2023

ePIC SVT DSC kickoff meeting

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ePIC-SVT - Berkeley...

Vertex layers

R&D activity in the INFN groups

INFN participates in the following projects for FY23:

- generic R&D:
 - ✓ INFN: ~0.4 Post-doc FTE = 34 kUSD, material = 15 kUSD
 - *Additive manufacturing of power and data redistribution layers on thin large-area silicon*
 - ✓ contact: G. Contin (TS)
- eRD111 – Silicon vertex (sensors excluded)
 - ✓ INFN: 0.25 Post-doc FTE = 20 kUSD, material = 10 kUSD
 - *Forming modules from stitched sensors*
 - ✓ contact: R. Turrisi (PD)
- eRD113 – Sensor development and characterization
 - ✓ INFN: 0.25 Post-doc FTE = 20 kUSD, material = 10 kUSD
 - *Progress in testing and characterization*
 - ✓ contact: D. Elia (BA)

R&D activity in the INFN groups

INFN participates in the following projects for FY23 (cont'd):

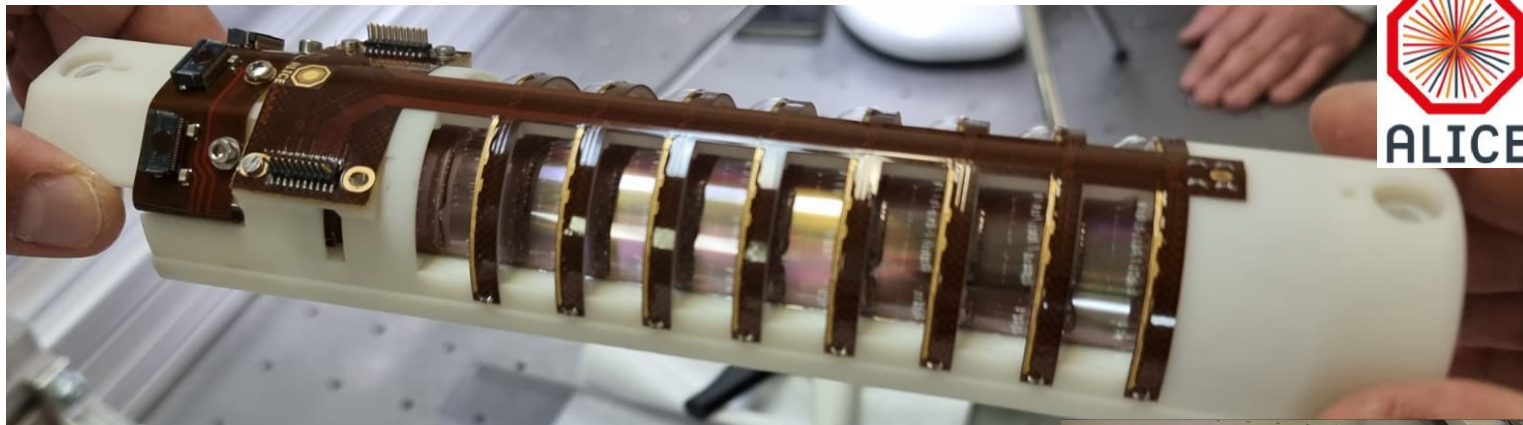
- status of administrative procedures:
 - ✓ approved by INFN CD, contracts (INFN-JLab/DOE sides) signed
 - ✓ status for the corresponding positions:
 - BA: call for a post-doc position (1y+1), expected to be out in July
 - PD: co-funding of a PhD position with Phys. Dept. (contact: P. Giubilato)
 - TS: looking for co-funding for a post-doc position

Plans for FY24:

- eRD104, eRD111, eRD113: call is out, proposal deadline July 7, 2023
- generic R&D: call is out, proposal deadline July 14, 2023
- INFN aim: get a similar second-year funding, in continuation to FY23

R&D activity in the INFN groups

ITS3 super-ALPIDE project in Bari:



Dummy-pad-super-ALPIDE#1 (40 μm)

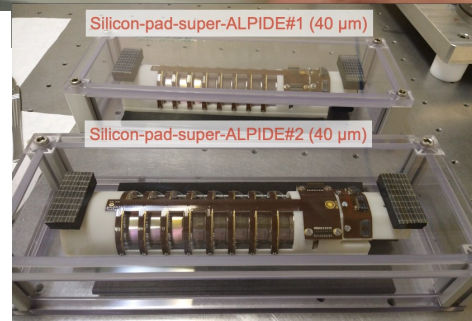
First complete assembly of a super-ALPIDE prototype based on real blank silicon (not electronics integrated) with metallic pad for bonding → Completed on 8/2/23

Dummy-pad-super-ALPIDE#21 (40 μm)

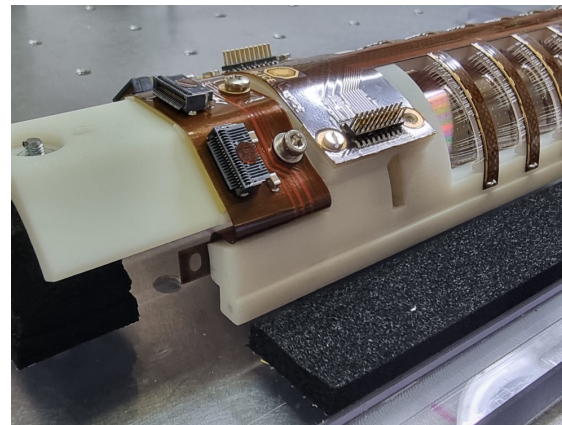
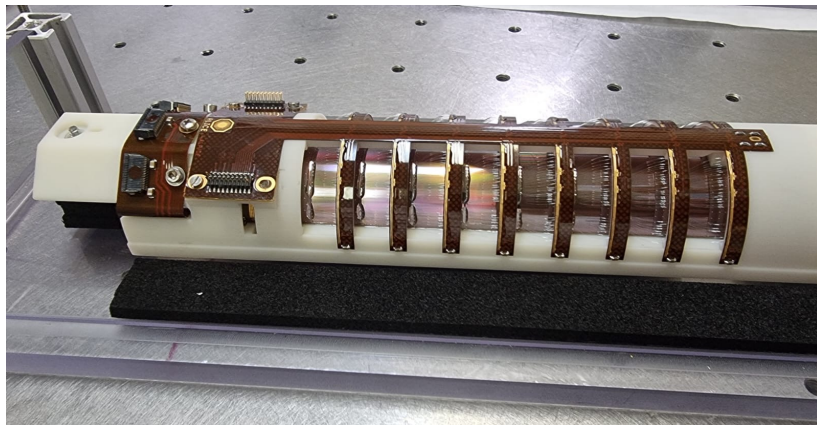
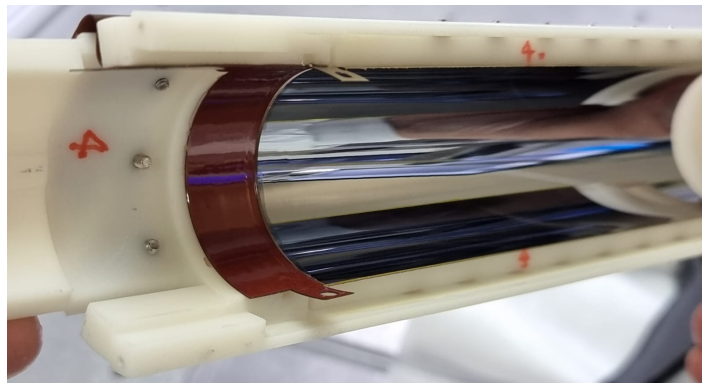
Second complete assembly of a super-ALPIDE prototype this time using carbon foam support structures → Completed on 14/3/23

Super-ALPIDE#11 (30 μm)

Assembly with working sensor failed (28/3) → Mandrel with improved quality surface under production

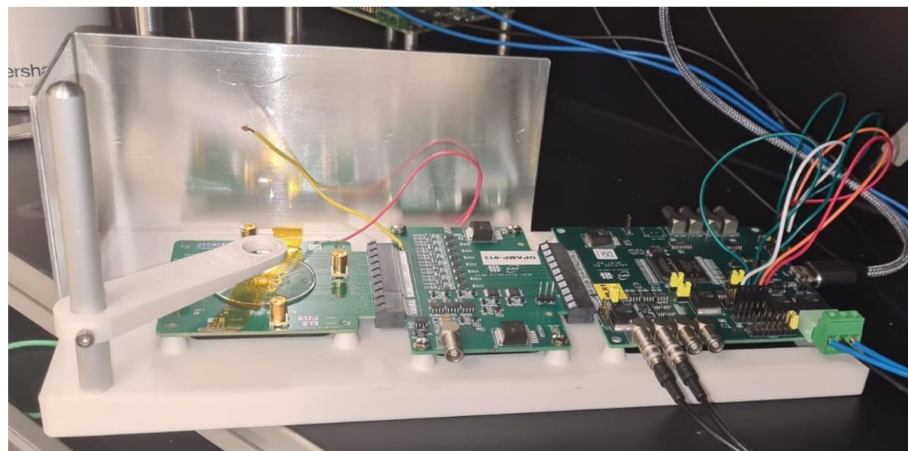


R&D activity in the INFN groups



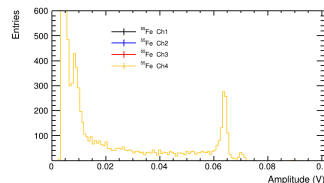
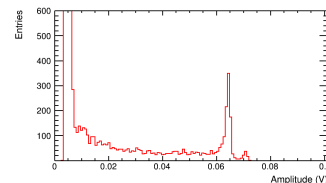
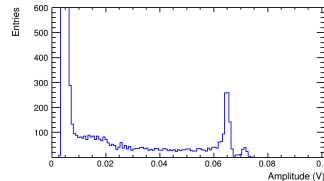
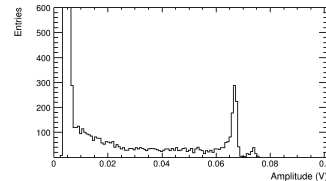
R&D activity in the INFN groups

MLR1 APTS OP-AMP characterization in Bari:



- Setup configured and verified
- Very first ^{55}Fe spectrum with low statistics, using the central 4 pixels of the matrix (acquired using an oscilloscope)
- Higher activity ^{55}Fe source under procurement
- Data acquisition software development

Low stat. ^{55}Fe spectrum



R&D activity in the INFN groups

Simulation activities in Bari (S. Kumar, A. Mastroserio):

- Event Display Tutorial (ROOT Based)
 - ✓ https://indico.bnl.gov/event/18213/contributions/73480/attachments/46166/78396/EventDisplay_ShyamKumar23Feb2023.pdf
- Smearing of Parameters in the Truth Seeding
 - ✓ https://indico.bnl.gov/event/18272/contributions/72753/attachments/45921/77608/EPIC_Meeting_Shyam9Feb23.pdf
- Studies of Number of Hits/Lever Arm
 - ✓ https://indico.bnl.gov/event/17924/contributions/72265/attachments/45681/77134/EPIC_Tracking_Meeting_Shyam26Jan2023.pdf
- Fast Simulation Studies with the EPIC Detector
 - ✓ https://indico.bnl.gov/event/17750/contributions/71187/attachments/44843/75637/EPIC_Tracking_Meeting_Shyam1Dec2022.pdf

R&D activity in the INFN groups

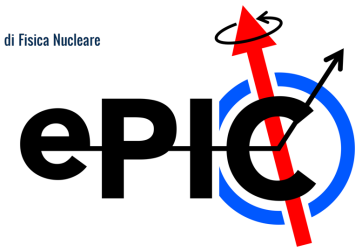
ITS3/ePIC activities in Padova and Trieste:

- Joint effort for MLR1 characterization after bending
- Two APTS were bent in Trieste along two different axis
- Tested in Padova with an X-ray source (^{55}Fe) for different depletion voltages and a comparison with a flat chip was performed
- More details in Rosario's presentation

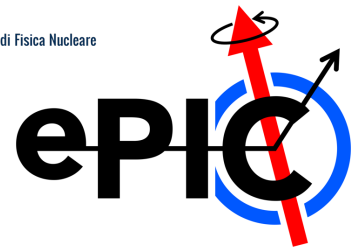
BACKUP



Istituto Nazionale di Fisica Nucleare
SEZIONE DI BARI



ePIC SVT layout and concept



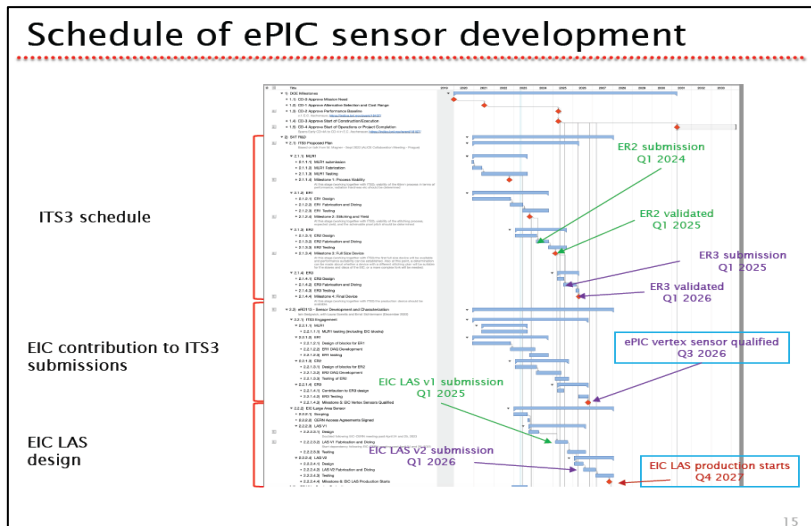
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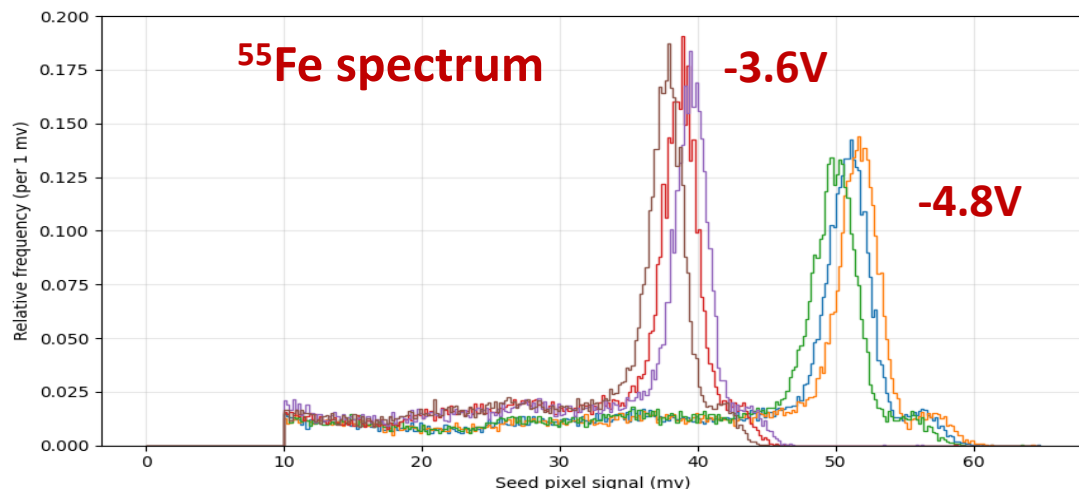
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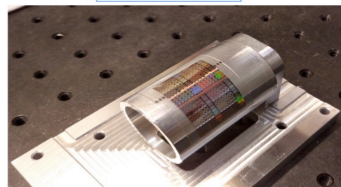
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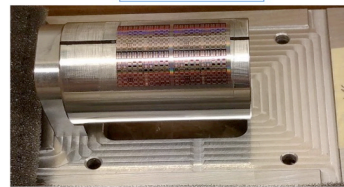


TS-001 bent along long edge



AF15P_W16B101

TS-004 bent along short edge



AF15P_W16B104

$I_{bias4} = 150 \mu\text{A}$
 $I_{bias3} = 200 \mu\text{A}$
 $V_{reset} = 500 \text{ mV}$

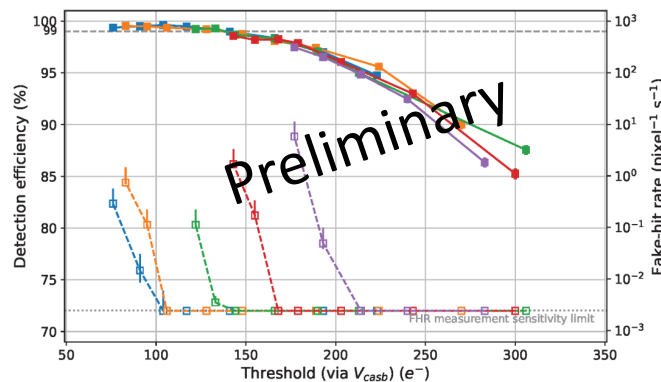
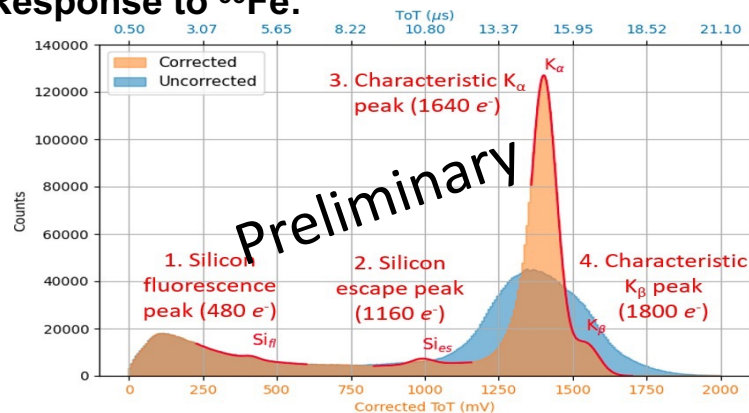
$V_{sub} = -4.8$, AF15P_W16B3
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 $V_{sub} = -3.6$, AF15P_W16B3
 $V_{sub} = -3.6$, AF15P_W16B101
 $V_{sub} = -3.6$, AF15P_W16B104



R&D activity in the INFN groups

Bending and testing 65 nm CMOS chips in Trieste:

Response to ^{55}Fe :



Bending:

